

Nernst effect in topological Dirac semimetals

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Dirac semimetals (DSM) are three dimensional analog of graphene with massless Dirac fermions as low energy electronic excitations. In contrast to Weyl semimetals (WSM), the point nodes in the bulk spectrum of topological DSMs have a vanishing Chern number, but can yet be stable due to the existence of crystalline symmetries such as uniaxial (discrete) rotation symmetry. We consider a model low-energy Hamiltonian appropriate for the recently discovered topological DSM Cd_3As_2 , and calculate the Nernst response within semiclassical Boltzmann dynamics in the relaxation time approximation. We show that, for small chemical potentials near the Dirac points, the low temperature, low magnetic field, Nernst response is dominated by *anomalous* Nernst effect (ANE), arising from a non-trivial profile of Berry curvature on the Fermi surface. Although the Nernst coefficient (both anomalous as well as conventional) vanish in the limit of zero magnetic field, the low temperature, low magnetic field, Nernst response, which has an almost step like profile near $\mathbf{B} = 0$, serves as an effective experimental probe of ANE in topological DSMs protected by crystalline symmetries.

I. INTRODUCTION

Dirac semimetals (DSM) are three-dimensional (3D) analog of graphene, with point nodes in the bulk energy spectrum supporting low energy excitations with relativistic energy momentum relations resembling massless Dirac fermions^{1,2}. In principle they can arise at the quantum critical point between a 3D topological insulator and a conventional insulator with fine tuning of an external parameter. Topological Dirac semimetals are stable 3D electron systems with bulk Dirac nodes protected by crystalline symmetries³⁻⁵. In DSM, owing to the simultaneous presence of time reversal and space inversion symmetries, the bulk energy bands are Kramers degenerate locally at each $\mathbf{k}$ ($E_{n,\sigma}(\mathbf{k}) = E_{n,-\sigma}(\mathbf{k})$). The Kramers degeneracy ensures that an accidental crossing between valence and conduction bands engenders a four-fold degenerate Dirac node. Such four-fold degenerate nodes in the bulk energy spectrum can be stable only in the presence of additional symmetries, such as uniaxial discrete crystal rotation symmetries C_n ⁵. This can be contrasted with three dimensional topological Weyl semimetals (WSM)^{1,6-8}, where (two-fold degenerate) Weyl nodes in the bulk energy spectrum are stable due to the existence of a non-zero Chern number invariant associated with each Weyl node. In DSM the simultaneous presence of time reversal and space inversion symmetry ensures that the Chern number vanishes for each Dirac node, which can in turn be thought as the superposition of a pair of Weyl nodes with equal and opposite chirality.

In recent studies several materials have been theoretically proposed to be topological DSMs^{3,6,9-11}. On the experimental side, Cd_3As_2 ¹²⁻¹⁹ and Na_3Bi ²⁰⁻²² have been experimentally confirmed to support three dimensional bulk Dirac nodes with linear energy spectrum. In this work we take a system with a pair of four-fold degenerate Dirac nodes on a high symmetry axis (which we choose as the k_z axis as the axis of C_n crystal rotation symmetry) as a prototypical topological DSM. The recently discovered DSMs, Cd_3As_2 and Na_3Bi , are both thought to be in this class. This class of DSMs are topological because, since the Dirac points appear on the high symmetry axis at $(k_x, k_y, k_z) = (0, 0, \pm k_{z0})$, the $k_z = 0$ plane can be considered as a gapped two-dimensional system with time

reversal and space invariance symmetries, allowing the definition of a 2D Z_2 invariant analogous to the 2D quantum spin Hall insulator. Additionally, since the system is invariant under a discrete rotation symmetry C_4 about the k_z axis, which is responsible for the stability of the Dirac points, one can define an additional integer topological invariant (mirror Chern number) on the $k_z = 0$ plane⁵. The mirror symmetry appears here as a result of the combination of space inversion symmetry and π rotation about the k_z axis, which follows from the existence of the C_4 symmetry.

Although topological DSMs have certain non-trivial topological properties such as surface Dirac fermions and zero energy Fermi loops, topological thermoelectric response such as anomalous Hall and Nernst effects, which depend on non-zero momentum space integrals of Berry curvature across surfaces in the Brillouin zone, must vanish in the limit of zero magnetic field, because of the existence of time reversal symmetry. Since anomalous Hall and Nernst conductivities arise from the transverse current response (odd under time reversal) to an applied longitudinal electric field and temperature gradient (even under time reversal), independent of an applied magnetic field, it follows that the anomalous conductivities must vanish in systems that preserve time reversal symmetry. This can also be understood from the fact that the Chern number of the Dirac nodes in a DSM, which measures the flux of the Berry curvature over closed surfaces around the Dirac node, is identically zero, and thus, in the absence of a magnetic field, the net flux of the Berry curvature vanishes everywhere in the Brillouin zone. In the presence of a magnetic field, however, time reversal symmetry is broken, and topological DSMs reduce to WSMs, evincing anomalous Hall and Nernst response, superimposed over the conventional conductivities which must also be present because of a non-zero magnetic field.

In this paper we focus on the Nernst effect (conventional as well as anomalous) in topological Dirac semimetals for small magnetic fields (of the order of a few Tesla) and small chemical potential within the framework of Boltzmann theory in the relaxation time approximation. In this limit, we find that the conventional Nernst response is small due to Sondheimer cancellation, and can be of either sign depending on temperature, but the anomalous Nernst response is large and positive

because of the peak in the Berry curvature in the limit of small chemical potentials. At low temperatures, the behavior of the total Nernst coefficient is characterized by an almost step like profile at $\mathbf{B} = 0$. However, exactly at $\mathbf{B} = 0$ there is no Nernst signal from either conventional or anomalous contributions, because of the restoration of time reversal symmetry. The measured Nernst coefficient, thus, is dominated almost entirely by the anomalous Nernst effect, at least in the limit of small temperatures. Our results have direct experimental relevance for Nernst and thermoelectric measurements on the available topological Dirac semimetals Cd_3As_2 and Na_3Bi . For related work on thermoelectric response, although not for topological DSMs with a pair of Dirac points as appropriate for Cd_3As_2 and Na_3Bi , see Ref. [24] and Ref. [25].

This paper is organized as follows. In Sec. II we introduce the low energy Hamiltonian appropriate for a topological DSM with a pair of Dirac points on a high symmetry axis. This model should serve as an effective description for the available topological DSM Cd_3As_2 . In Sec. III we briefly sketch the derivation of Nernst conductivity within Boltzmann theory description in relaxation time approximation in the presence of a non-trivial Berry curvature. In the presence of a non-zero magnetic field, the Nernst response of topological DSMs comprise conventional as well as anomalous components, which are then described in Sec. IV and Sec. V, respectively. Our central results, plots for the total Nernst conductivity (conventional as well as anomalous) as a function of the applied magnetic field at several different temperatures are displayed in Fig. 5. We end with a brief discussion and conclusion in Sec. VI.

II. HAMILTONIAN FOR TOPOLOGICAL DSM

The effective low energy Hamiltonian for the Dirac semimetal Cd_3As_2 , in the basis $|s, \uparrow\rangle$, $|p_x + ip_y, \uparrow\rangle$, $|s, \downarrow\rangle$, $|p_x - ip_y, \downarrow\rangle$ can be written as^{5,23}

$$H_{\mathbf{k}} = a(\mathbf{k})\sigma_z s_0 + b(\mathbf{k})\sigma_x s_z + c(\mathbf{k})\sigma_y s_0 + d(\mathbf{k})\sigma_x s_x + e(\mathbf{k})\sigma_x s_y \quad (1)$$

In Eq. 1, σ and s are Pauli matrices representing the orbital degree of freedom and spin degree of freedom respectively. The matrix $s_0 \equiv I_2$ in spin space. The functions $a(\mathbf{k}) - e(\mathbf{k})$ are defined as

$$a(\mathbf{k}) = m_0 - m_1 k_z^2 - m_2 (k_x^2 + k_y^2), \quad (2)$$

$$b(\mathbf{k}) = \eta k_x, \quad (3)$$

$$c(\mathbf{k}) = -\eta k_y, \quad (4)$$

$$d(\mathbf{k}) = (\beta + \gamma)k_z(k_y^2 - k_x^2), \quad (5)$$

$$e(\mathbf{k}) = -2(\beta - \gamma)k_z k_x k_y, \quad (6)$$

The parameters m_0 , m_1 , m_2 , η , β and γ depend on the material. This Hamiltonian produces two Dirac points at $\mathbf{K} = (0, 0, \pm\sqrt{m_0/m_1})$ where the energy dispersion exactly vanishes. Fig. 1 shows the band structure for the prototype DSM obtained by numerically diagonalizing Eq. 1. The effect of an external magnetic field $\mathbf{B}$, coupling to the spin degree of

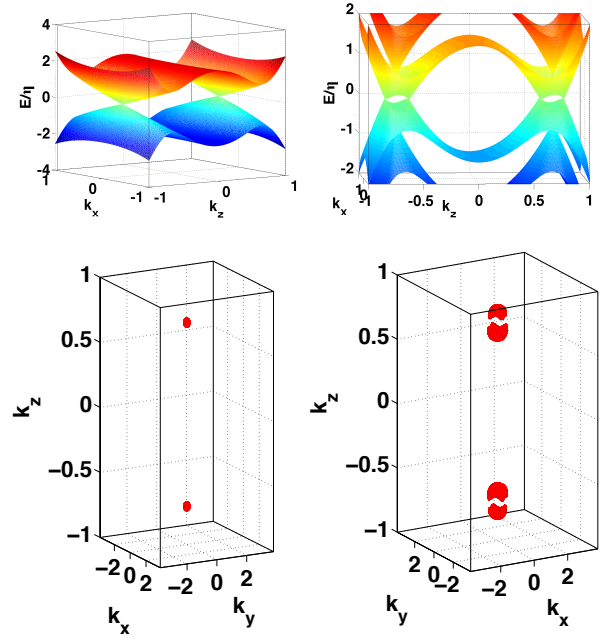


FIG. 1. *Left panel:* Band structure of the Dirac semimetal given by Eq. 1 consisting of two four-fold degenerate Dirac points at $(0, 0, \pm\sqrt{m_0/m_1})$. *Right panel:* The spin-degeneracy is lifted by a magnetic field producing a total of four doubly-degenerate Weyl points located at $(0, 0, \pm\sqrt{(\pm b_z + m_0)/m_1})$. The parameters used were $m_2 = -\eta/5$, $m_0 = -2\eta$, $m_1 = -4\eta$, $\beta = -\eta/5$, $\gamma = \eta$, and $b_z = 0$ ($b_z = 3\eta/5$) for the (left) right panels. *Bottom panels:* Fermi surfaces for the doped Dirac (Weyl) metals on the left (right), when $b_z = 0$ ($b_z = 3\eta/5$), for $\mu = 0.16\eta$. The parameter η was chosen to be $\eta = 50\text{meV}$.

freedom can be now introduced by adding the Zeeman term $H_Z = b_z \sigma_0 s_z$ in the Hamiltonian, where $b_z = -\boldsymbol{\mu} \cdot \mathbf{B}$, $\boldsymbol{\mu}$ being the spin-magnetic moment, $\boldsymbol{\mu} = -\mu_B g_s \mathbf{s}/\hbar$. This now produces a TR broken Weyl semimetal, with four Weyl points located at $(0, 0, \pm\sqrt{(\pm b_z + m_0)/m_1})$. Each Weyl node now carries a non-trivial Chern number, which is also its chirality quantum number. Fig. 1 also shows the band structure for the TR broken Weyl semimetal. Near half-filling, the Fermi surface for a Dirac semimetal consists of two disconnected spheres, as shown in Fig. 1, for $\mu > 0$. The Zeeman field then splits each sphere into two disconnected surfaces around each Weyl point. Although the topological DSM described by the Hamiltonian in Eq. 1 is characterized by a vanishing Berry curvature, the topological WSM described by $H = H_{\mathbf{k}} + H_Z$ has a nontrivial profile of Berry curvature in the Brillouin zone. The expression for the Berry curvature is given by²⁶,

$$\Omega_{ab}^n = i \sum_{n \neq m} \frac{\langle n | \partial H / \partial k_a | m \rangle \langle m | \partial H / \partial k_b | n \rangle - (a \leftrightarrow b)}{(\epsilon_n - \epsilon_m)^2} \quad (7)$$

The Hamiltonian $H = H_{\mathbf{k}} + H_Z$ produces four bands which we have labeled by the index n in the above expression. Also, $|n\rangle$ is a Bloch eigenstate of the Hamiltonian H with eigenvalue ϵ_n . In Fig. 2 we have plotted the Berry curvature distribution

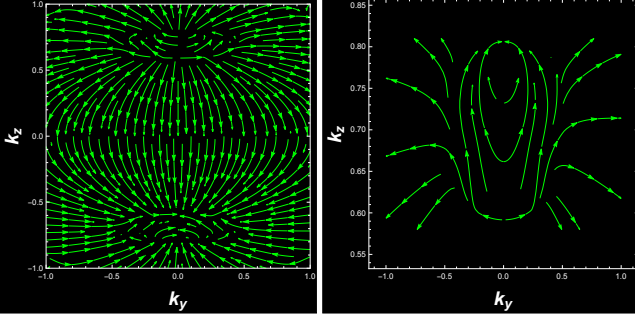


FIG. 2. Berry curvature flux for the topological DSM described by the Hamiltonian given in Eq. 1, in the presence of a magnetic field (in the presence of a magnetic field the system is effectively a Weyl semimetal). The plot on the left shows the Berry curvature in the plane $k_x = 0$ suggesting a sink and source of Berry flux near each Dirac point at $(0, 0, \pm\sqrt{m_0/m_1})$. On the right, we have the Berry curvature distribution zoomed in near a single Dirac point $(0, 0, +\sqrt{m_0/m_1}) \approx (0, 0, 0.7)$ (now split into two Weyl points at $\approx (0, 0, 0.6)$, and $\approx (0, 0, 0.8)$ when $b_z \neq 0$). A similar distribution (not shown specifically by zooming) exists around the other Dirac point $(0, 0, -\sqrt{m_0/m_1})$.

bution for the Weyl semimetal phase described by the Hamiltonian $H = H_{\mathbf{k}} + H_Z$.

III. NERNST EFFECT IN THE PRESENCE OF BERRY CURVATURE

The Nernst effect refers to the generation of a transverse electric field in the presence of a longitudinal temperature gradient. Conventionally, the Nernst effect can occur only in the presence of an external magnetic field, which provides a transverse velocity to the electrons by the Lorentz force. However, a non-trivial Berry curvature Ω , can also give rise to a Nernst response as a result of an anomalous velocity term²⁷. In the presence of an external electric field $\mathbf{E}$ and a temperature gradient $-\nabla T$, one can write the following linear response relations for the charge current $\mathbf{J}$ and thermal current $\mathbf{Q}$:

$$\begin{pmatrix} \mathbf{J} \\ \mathbf{Q} \end{pmatrix} = \begin{pmatrix} \hat{\sigma} & \hat{\alpha} \\ \hat{\alpha} & \hat{\kappa} \end{pmatrix} \begin{pmatrix} \mathbf{E} \\ -\nabla T \end{pmatrix} \quad (8)$$

The tensors $\hat{\alpha}$ and $\hat{\alpha}$ are related to each other by Onsager's relation: $\hat{\alpha} = T\hat{\alpha}$. In the absence of charge current ($\mathbf{J} = 0$), we have $\mathbf{E} = \hat{\sigma}^{-1}\hat{\alpha}\nabla T$. The Nernst coefficient ν can be derived to be

$$\nu = \frac{E_y}{(-dT/dx)} = \frac{\alpha_{xy}\sigma_{xx} - \alpha_{xx}\sigma_{xy}}{\sigma_{xx}^2 + \sigma_{xy}^2}, \quad (9)$$

Berry curvature significantly contributes to the conductivities σ and α . In the presence of Berry curvature $\Omega_{\mathbf{k}}$, the semi-classical equation of motion for an electron takes the form^{27,28} $\dot{\mathbf{r}} = \frac{1}{\hbar} \frac{\partial \epsilon(\mathbf{k})}{\partial \mathbf{k}} + \frac{\dot{\mathbf{p}}}{\hbar} \times \Omega_{\mathbf{k}}$. The first term is the familiar relation between semi-classical velocity $\dot{\mathbf{r}}$ and the band energy dispersion $\epsilon(\mathbf{k})$. The second term is the anomalous transverse

velocity term originating from $\Omega(\mathbf{k})$. In the presence of electric and magnetic fields we also have the standard relation $\dot{\mathbf{p}} = e\mathbf{E} + e\dot{\mathbf{r}} \times \mathbf{B}$. These two coupled equations for $\dot{\mathbf{r}}$ and $\dot{\mathbf{p}}$ can be solved together to obtain^{29,30}

$$\dot{\mathbf{r}} = D(\mathbf{B}, \Omega_{\mathbf{k}}) \left(\mathbf{v}_{\mathbf{k}} + \frac{e}{\hbar} (\mathbf{E} \times \Omega_{\mathbf{k}}) + \frac{e}{\hbar} (\mathbf{v}_{\mathbf{k}} \cdot \Omega_{\mathbf{k}}) \mathbf{B} \right) \quad (10)$$

$$\dot{\mathbf{p}} = D(\mathbf{B}, \Omega_{\mathbf{k}}) \left(e\mathbf{E} + \frac{e}{\hbar} (\mathbf{v}_{\mathbf{k}} \times \mathbf{B}) + \frac{e^2}{\hbar} (\mathbf{E} \cdot \mathbf{B}) \Omega_{\mathbf{k}} \right) \quad (11)$$

where $D(\mathbf{B}, \Omega_{\mathbf{k}}) = (1 + e(\mathbf{B} \cdot \Omega_{\mathbf{k}})/\hbar)^{-1}$.

Using the semi-classical Boltzmann equations in the presence of a non-zero electric and magnetic field and a Berry curvature, one can derive the following thermoelectric and charge conductivity tensors (σ and α) which include contributions from the $\mathbf{B}$ and $\Omega_{\mathbf{k}}$ ^{24,25,31,32}.

$$\sigma_{xx} = -e^2 \int [d\mathbf{k}] v_x^2 \tau \left(-\frac{\partial f_{eq}}{\partial \epsilon} \right) (c_x - D) \quad (12)$$

$$\begin{aligned} \sigma_{xy} = & -e^2 \int [d\mathbf{k}] (v_y^2 c_y + v_x v_y (c_x - D)) \tau \left(-\frac{\partial f_{eq}}{\partial \epsilon} \right) \\ & + \frac{e^2}{\hbar} \int [d\mathbf{k}] \Omega_z f_0 \end{aligned} \quad (13)$$

$$\alpha_{xx} = e \int [d\mathbf{k}] v_x^2 \left(\tau \frac{\epsilon - \mu}{T} \left(-\frac{\partial f_{eq}}{\partial \epsilon} \right) (c_x - D) \right) \quad (14)$$

$$\begin{aligned} \alpha_{xy} = & e \int [d\mathbf{k}] (v_y^2 c_y + (c_x - D) v_x v_y) \left(\tau \frac{\epsilon - \mu}{T} \left(-\frac{\partial f_{eq}}{\partial \epsilon} \right) \right) \\ & + \frac{k_B e}{\hbar} \int [d\mathbf{k}] \Omega_z s_{\mathbf{k}} \end{aligned} \quad (15)$$

where $v_x \equiv \hbar^{-1} \partial \epsilon_{\mathbf{k}} / \partial k_x$, and $v_y \equiv \hbar^{-1} \partial \epsilon_{\mathbf{k}} / \partial k_y$ are the band velocities, ϵ_F is the Fermi energy, τ is the scattering time, $[d\mathbf{k}] \equiv \frac{d^3 \mathbf{k}}{(2\pi)^3}$, f_0 is the Fermi-Dirac distribution, $s_{\mathbf{k}} = -f_0 \log f_0 - ((1 - f_0) \log(1 - f_0))$ is entropy density for the free electron gas. The scattering time τ usually has a non-trivial energy and momentum dependence. In this work we have assumed τ to be a phenomenological constant, which suffices for our discussion and does not change our qualitative results. The correction factors c_x , c_y , and D in Eq. 12-15 have lengthy expressions and have been discussed elsewhere²⁴. In the absence of Berry curvature $D \rightarrow 1$, and $c_x - D \rightarrow -1$ (up to zeroth order in $\mathbf{B}$). It is important to note that the longitudinal conductivities (σ_{xx} , α_{xx}) are also modified from their standard Boltzmann expressions due to Berry curvature corrections. If these corrections can be ignored, then Eq. 12, 14 reduce to the following³³

$$\sigma_{xx} = e^2 \int [d\mathbf{k}] v_x^2 \tau \left(-\frac{\partial f_{eq}}{\partial \epsilon} \right), \quad (16)$$

$$\alpha_{xx} = -\frac{e}{T} \int [d\mathbf{k}] v_x^2 \tau (\epsilon - \mu) \left(-\frac{\partial f_{eq}}{\partial \epsilon} \right), \quad (17)$$

Similarly, if the Berry curvature corrections to the conventional $\mathbf{B}$ -dependent conductivities are ignored, then Eq. 13, 15

reduce to^{27,33}

$$\sigma_{xy} = -\frac{e^3\tau^2B}{\hbar} \int [d\mathbf{k}] \left(-\frac{\partial f_0}{\partial \epsilon} \right) \left(\frac{v_x^2 \partial^2 \epsilon}{\partial k_y^2} - \frac{v_x v_y \partial^2 \epsilon}{\partial k_x \partial k_y} \right) + \frac{e^2}{\hbar} \int [d\mathbf{k}] \Omega_z f_0 \quad (18)$$

$$\alpha_{xy} = \frac{e^3\tau^2B}{T\hbar} \int [d\mathbf{k}] (\epsilon - \mu) \left(-\frac{\partial f_0}{\partial \epsilon} \right) \left(\frac{v_x^2 \partial^2 \epsilon}{\partial k_y^2} - \frac{v_x v_y \partial^2 \epsilon}{\partial k_x \partial k_y} \right) + \frac{k_B e}{\hbar} \int [d\mathbf{k}] \Omega_z s_{\mathbf{k}} \quad (19)$$

IV. CONVENTIONAL NERNST RESPONSE

The conventional Nernst coefficient can be deduced by using Eqs. 16-19 in the limit $\Omega_{\mathbf{k}} \rightarrow 0$, and the definition of ν (Eq. 9). In conventional metals, the quasiparticle Nernst coefficient is usually small as a result of Sondheimer cancellation^{34,35}. For example, the Nernst coefficient ν/B is $3.9nV/KT$ for Al, and $-21.6nV/KT$ for Cu. In the limit of small μ , the conventional Nernst coefficient for a linearized Dirac Hamiltonian ($\epsilon_{\mathbf{k}} = \hbar v_F \boldsymbol{\sigma} \cdot \mathbf{k}$) can be derived to be²⁴

$$\vartheta_0 = -\frac{\pi^2}{3} \frac{k_B^2 T}{e} \frac{e B v_F^2 \tau_0}{\hbar}, \quad (20)$$

where τ_0 parametrizes the scattering time. If τ_0 is large, then the Nernst coefficient can also be parametrically large even in the presence of Sondheimer's cancellation. For our model and the chosen parameters, using Eqs. 16-19 with $\Omega_{\mathbf{k}} \rightarrow 0$, we found that the conventional Nernst coefficient is at least two orders of magnitude smaller than the anomalous Berry curvature dependent response, due to the peaks in the Berry curvature near $\mu = 0$ at the four nodal Weyl points (see Fig. 3). Importantly, the sign of the Nernst coefficient is not directly related to the sign of the dominant charge carriers in the material. It can be either positive or negative for an electron or a hole-like Fermi surface, depending on the detailed Fermi surface topology^{35,36}. Our model produces a negative conventional Nernst signal (for positive b_z) at low temperatures ($T \sim 10K$), and a positive Nernst signal (for positive b_z) at higher temperatures ($T \sim 100K$). Further, electron ($\mu > 0$) or hole ($\mu < 0$) doping does not change the sign of the conventional Nernst coefficient.

Though the conventional quasiparticle Nernst signal is known to be small, the Nernst effect has been used as a probe for high- T_c cuprate superconductors, where vortex movement is well-known to give rise to a large *positive* Nernst signal^{35,37}. This also forms the commonly used convention to assign a definite sign to a Nernst signal. We have followed this sign convention in our work.

At low temperatures, the Mott relation gives α_{ij} as a derivative of σ_{ij} with respect to the chemical potential³³. Specifically,

$$\alpha_{ij} = -\frac{\pi^2}{3} \frac{k_B^2 T}{e} \frac{\partial \sigma_{ij}}{\partial \mu} \quad (21)$$

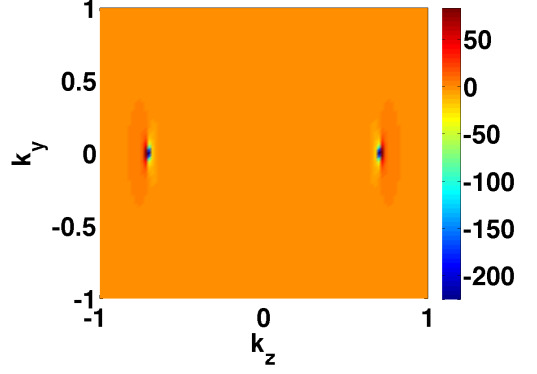


FIG. 3. Berry curvature Ω_z in the $k_x = 0$ plane for the Weyl semimetal phase of the Hamiltonian in Eq. 1, for $b_z = \eta/5$. The Berry curvature peaks around the nodal (Weyl) points on the k_z axis. For a small chemical potential, when the Fermi surface just encloses the Weyl points, the Nernst response is primarily dominated by the anomalous Berry curvature dependent contributions.

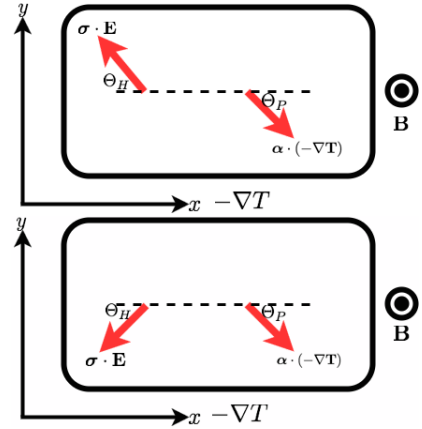


FIG. 4. *Top panel:* Sondheimer's cancellation for conventional quasiparticle Nernst effect. The magnitudes of the Hall angle Θ_H and the Peltier angle Θ_P are close to each other, with $\text{sgn}(\Theta_H) = \text{sgn}(\Theta_P)$, resulting in a small Nernst signal in the presence of a longitudinal temperature gradient $-\nabla T$ and a perpendicular magnetic field $\mathbf{B}$. The red arrows represent the current direction due to the electric field and temperature gradient. *Bottom panel:* The Hall and the Peltier angles no longer have the same signs for the anomalous Nernst response in a Dirac semimetal, resulting in no net Sondheimer's cancellation. The magnetic field breaks TR symmetry giving rise to a Weyl system with a measurable Nernst signal (electric field generated in the y direction for a temperature gradient $-\nabla T$ in the x direction), which is primarily anomalous response due to the peaking of the Berry curvature for small chemical potentials.

The Mott relation (at least at low temperatures) remains valid for both conventional and anomalous conductivities. Using the Mott relation, the Nernst coefficient ν can be derived to be

$$\nu = -\frac{\pi^2}{3} \frac{k_B^2 T}{e} \frac{\partial \Theta_H}{\partial \mu}, \quad (22)$$

where $\Theta_H = \sigma_{xy}/\sigma_{xx}$ is the Hall angle, in the limit $\sigma_{xy} \ll$

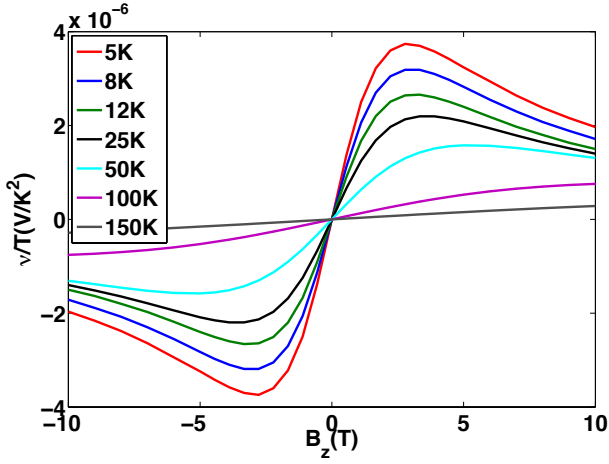


FIG. 5. Nernst coefficient (ν/T) as a function of applied magnetic field $\mathbf{B}$, for the Dirac semimetal at $\mu = +\eta/5$ (with an electron-like Fermi surface). The full Nernst coefficient has been plotted, though the response is primarily dominated by the anomalous contribution. At lower temperatures, the behavior is characterized by an almost step like profile at $\mathbf{B} = 0$. However, exactly at $\mathbf{B} = 0$ there is no Nernst signal from either conventional or anomalous contributions. The estimated Nernst coefficient is of the order $\sim \mu V/K^2$.

σ_{xx} . Expanding $\partial\Theta_H/\partial\mu$, we have

$$\begin{aligned} \nu &= -\frac{\pi^2}{3} \frac{k_B^2 T}{e\sigma_{xx}^2} \left(\sigma_{xx} \frac{\partial\sigma_{xy}}{\partial\mu} - \sigma_{xy} \frac{\partial\sigma_{xx}}{\partial\mu} \right) \\ &= \frac{\alpha_{xx}}{\sigma_{xx}} (\Theta_P - \Theta_H), \end{aligned} \quad (23)$$

where Θ_P is the Peltier angle, with $\Theta_P = \alpha_{xy}/\alpha_{xx}$. For a Dirac node having a spherical Fermi surface the longitudinal conductivity (σ_{xx}), which depends on the area of the Fermi surface, increases (decreases) for an electron (hole) doped system, with increasing μ . The Hall conductivity (σ_{xy}), which correlates with the Fermi surface curvature is negative (positive) for electron (hole) doping. However, $\sigma_{xx} > 0$, and $\partial\sigma_{xy}/\partial\mu < 0$ for both electron and hole-like Fermi surfaces. Hence the Hall and Peltier angles carry the same sign in Eq. 23. Sondheimer's cancellation^{34,35,37} occurs when the angles Θ_H and Θ_P are close to each other in magnitude and have the same sign, $\text{sgn}(\Theta_H) = \text{sgn}(\Theta_P)$. This is the case in our calculation of the conventional Nernst response, resulting in a conventional Nernst coefficient much smaller in magnitude than the anomalous Nernst coefficient, which does not undergo Sondheimer cancellation. This has also been illustrated in Fig. 4, where the currents due to charge conductivity tensor σ and the Peltier coefficient α , oppose each other, in the case of conventional Nernst response.

V. ANOMALOUS NERNST RESPONSE

In the presence of Berry curvature ($\Omega_{\mathbf{k}}$), Eq. 16-19 can be used to compute the Nernst coefficient. The anomalous trans-

verse conductivities can be extracted to be

$$\sigma_{xy}^A = \frac{e^2}{\hbar} \int [d\mathbf{k}] \Omega_z f_0, \quad (24)$$

$$\alpha_{xy}^A = \frac{k_B e}{\hbar} \int [d\mathbf{k}] \Omega_z s_{\mathbf{k}}, \quad (25)$$

The quantity σ_{xy}^A depends on the Berry curvature of the filled bands, but α_{xy}^A is a Fermi surface quantity, because $s_{\mathbf{k}}$ is zero for completely filled and empty bands. It is for this reason, that an insulator can give rise to an anomalous Hall response (σ_{xy}^A), but not α_{xy}^A . The Dirac semimetal itself does not result in an anomalous Nernst signal, as the net flux of Berry curvature exactly vanishes everywhere in the Brillouin zone. Under the application of an external magnetic field $\mathbf{B}$, each Dirac node splits into two Weyl nodes, and near half-filling a Weyl semimetal is realized. The transition from a Dirac semimetal to a Weyl semimetal under the application of a magnetic field has been highlighted in Fig. 1. A Weyl semimetal has a non-trivial distribution of magnetic flux (as illustrated in Fig. 2) and Fig. 3, and an anomalous Nernst signal can thus be expected.

Unlike the conventional Hall conductivity (σ_{xy}), the anomalous Hall conductivity (σ_{xy}^A) has a different behavior with respect to changes in the chemical potential. The magnitude of the anomalous Hall conductivity peaks near the band-touching points at $\mu = 0$, as in the vicinity of these points the Berry curvature is sharply peaked (Fig. 3). For small electron or hole doping, when $\mu \neq 0$, the Berry curvature effects reduce and the magnitude of σ_{xy}^A decreases. The Mott relation (Eq. 21), thus produces opposite signs of α_{xy}^A for electron (positive sign) and hole doping (negative sign). The anomalous Peltier coefficient $\alpha_{xy}^A = 0$ for an arbitrary μ , if the underlying quasiparticle dispersion is that of an unbounded linearized spectrum of Weyl fermions, because then σ_{xy}^A is robust to changes in the Fermi energy^{24,25}. Specifically, $\sigma_{xy}^A = \frac{e^2}{2\pi^2\hbar} k_0$ for a simple linearized model of a Weyl semimetal with node separation given by k_0 in momentum space^{8,38,39}. However, for a physical Weyl semimetal with an ultraviolet cutoff, α_{xy}^A remains generically finite²⁴.

Now we can note that for the anomalous conductivities ($\sigma_{xy}^A, \alpha_{xy}^A$), the Hall (Θ_H) and Peltier (Θ_P) angles, irrespective of their own magnitudes (which may or may not be of the same order), have opposite signs of each other, $\text{sgn}(\Theta_H) = -\text{sgn}(\Theta_P)$ (contrasted with the case of conventional Nernst response where $\text{sgn}(\Theta_H) = \text{sgn}(\Theta_P)$). This suggests that Sondheimer's cancellation does not take place, generating a measurable anomalous Nernst signal, stronger than the conventional quasiparticle Nernst signal. This feature has also been illustrated in Fig. 4. The angles Θ_H and Θ_P carrying opposite signs result in a net non-zero electric field E_y in the transverse direction. The overall sign of the anomalous Nernst signal in the present case correlates with the sign of the anomalous Hall conductivity σ_{xy}^A .

We numerically compute the full Nernst coefficient, including contributions from the the conventional $\mathbf{B}$ -dependent responses and the anomalous responses, using Eq. 12-15. In Fig. 5, we plot the estimated Nernst coefficient (ν/T) as a

function of external magnetic field $\mathbf{B}$ applied in the $\hat{z}$ direction. As suggested by our previous discussion, the Nernst response is primarily dominated by the anomalous contribution. This is further confirmed by our numerical results, where the conventional Nernst coefficient was found to be at least two orders of magnitude smaller than the anomalous Nernst coefficient. At lower temperatures ($\sim T < 100K$), the behavior of the Nernst coefficient (ν/T) is characterized by an almost step like profile at $\mathbf{B} = 0$. The distribution of the flux of the Berry curvature determines the anomalous Hall conductivity σ_{xy}^A . For $\mathbf{B} < 0$, $\sigma_{xy}^A < 0$, and for $\mathbf{B} > 0$, $\sigma_{xy}^A > 0$. Exactly at $\mathbf{B} = 0$, one does not expect a finite σ_{xy}^A , or a finite ν , as $\Omega_{(\mathbf{B}=0)} = 0$. As pointed out before, the sign of ν directly correlates with the sign of σ_{xy}^A .

VI. CONCLUSIONS

Three dimensional topological Dirac semimetals are characterized by nodes in the bulk energy spectrum with a vanishing Chern number. Because of the vanishing flux of the Berry curvature through any surface in the Brillouin zone, anomalous Hall and Nernst conductivities vanish in a topological DSM in the absence of a magnetic field. In the presence of a magnetic field, however, a topological DSM reduces to a Weyl semimetal, evincing a non-zero Hall and Nernst response, which have contributions from both conventional as well as anomalous (Berry curvature mediated) components.

In this paper we consider a topological DSM with a pair of Dirac nodes on a high symmetry axis (axis of four fold rotational symmetry, C_4), which is an appropriate description of the experimentally realized Dirac semimetal Cd_3As_2 . For this system we compute the total Nernst coefficient (conventional as well as anomalous) in the presence of a small finite magnetic field (a few Tesla) and small chemical potential, within the Boltzmann description in the relaxation time approximation. We find that the conventional Nernst response is typically small due to Sondheimer cancellation, and can be of either sign depending on temperature, small and negative at low temperatures (~ 10 K), and small and positive at higher temperatures (~ 100 K). In contrast, we find that the anomalous Nernst response is large and positive because of the peaking of the Berry curvature in the limit of small chemical potentials and due to the absence of Sondheimer cancellation. Our calculated anomalous Nernst coefficient is almost two orders of magnitude larger than the conventional Nernst coefficient at similar temperatures and magnetic field. The measured Nernst coefficient, thus, is expected to be dominated almost entirely by the anomalous Nernst effect, at least in the limit of small temperatures. At low temperatures, the behavior of the total Nernst coefficient is characterized by an almost step like profile at $\mathbf{B} = 0$. However, exactly at $\mathbf{B} = 0$ there is no Nernst signal, from either conventional or anomalous contributions, because of the restoration of time reversal symmetry. Our results have direct experimental relevance for Nernst and thermoelectric measurements on the experimentally available topological DSMs Cd_3As_2 and Na_3Bi .

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